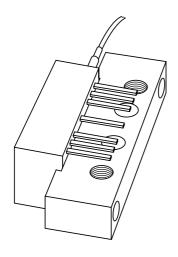
DISCRETE SEMICONDUCTORS

DATA SHEET



BGE883BOOptical receiver module

Product specification Supersedes data of 2000 Apr 10 2001 Sep 27





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FEATURES

- · Excellent linearity
- · Low noise
- · Excellent flatness
- Standard CATV outline
- Rugged construction
- Gold metallization ensures excellent reliability.

APPLICATIONS

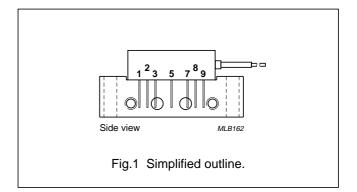
 CATV systems operating in the 40 to 860 MHz frequency range.

DESCRIPTION

Hybrid high dynamic range optical receiver module in a SOT115U package operating at a voltage supply of 24 V (DC). The module contains a monomode optical input suitable for wavelengths from 1290 to 1600 nm, a terminal to monitor the pin diode current and an electrical output with an impedance of 75 Ω .

PINNING - SOT115U

PIN	DESCRIPTION	
1	monitor current	
2	common	
3	common	
5	+V _B	
7	common	
8	common	
9	output	



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
f	frequency range		40	860	MHz
S ₂₂	output return losses	f = 40 to 860 MHz	17	_	dB
	optical input return losses		45	_	dB
d_2	second order distortion	f = 324.25 MHz	_	-76	dBc
F	equivalent noise input	f = 40 to 860 MHz	_	13	pA/√Hz
I _{tot}	total current consumption (DC)	V _B = 24 V	175	205	mA

HANDLING

Fibreglass optical coupling: maximum tensile strength = 5 N; minimum bending radius = 35 mm.

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
f	frequency range		40	860	MHz
T _{stg}	storage temperature		-40	+85	°C
T _{mb}	operating mounting base temperature		-20	+85	°C
P _{in}	optical input power	continuous	_	5	mW
ESD	ESD sensitivity	human body model; R = 1.5 k Ω ; C = 100 pF	500	_	V

CHARACTERISTICS

Table 1 Bandwidth 40 to 860 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 30 \,^{\circ}\text{C}$; $Z_L = 75 \,^{\circ}\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
S	responsivity	$\lambda = 1300 \text{ nm}$	400	-	V/W
FL	flatness of frequency response		_	±0.5	dB
S ₂₂	output return losses	f = 40 to 860 MHz	17	-	dB
	optical input return losses		45	-	dB
d ₂	second order distortion	note 1	_	-76	dB
d ₃	third order distortion	note 2	_	-92	dB
		note 3	_	-80	dB
F	equivalent noise input	f = 40 MHz to 860 MHz	_	13	pA/√Hz
Sλ	spectral sensitivity	$\lambda = 1310 \pm 20 \text{ nm}$	0.85	-	A/W
		$\lambda = 1550 \pm 20 \text{ nm}$	0.9	-	A/W
λ	optical wavelength		1290	1600	nm
L	length of optical fibre	fibre; SM type; 9/125 μm	1	_	m
I _{tot}	total current consumption (DC)	V _B = 24 V	175	205	mA

Notes

1. Two laser test; each laser with 40% modulation index;

 $f_p = 135 \text{ MHz}; P_p = 0.5 \text{ mW};$ $f_q = 189.25 \text{ MHz}; P_q = 0.5 \text{ mW};$

measured at $f_p + f_q = 324.25 \text{ MHz}.$

Three laser test; each laser with 40% modulation index;

 $f_p = 326.25 \text{ MHz}; P_p = 0.33 \text{ mW};$

 $f_q = 333.25 \text{ MHz}; P_q = 0.33 \text{ mW};$

 $f_r = 335.25 \text{ MHz}$; $P_r = 0.33 \text{ mW}$;

measured at $f_p + f_q - f_r = 324.25$ MHz.

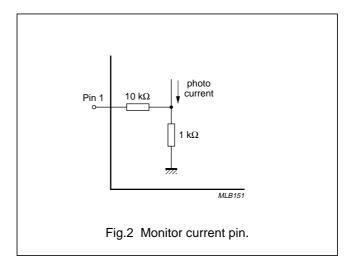
Three laser test; each laser with 50% modulation index;

 $f_p = 326.25 \text{ MHz}; P_p = 0.53 \text{ mW};$

 $f_q = 333.25 \text{ MHz}; P_q = 0.53 \text{ mW};$

 $f_r = 335.25 \text{ MHz}; P_r = 0.53 \text{ mW};$

measured at $f_p + f_q - f_r = 324.25$ MHz.



Philips Semiconductors Product specification

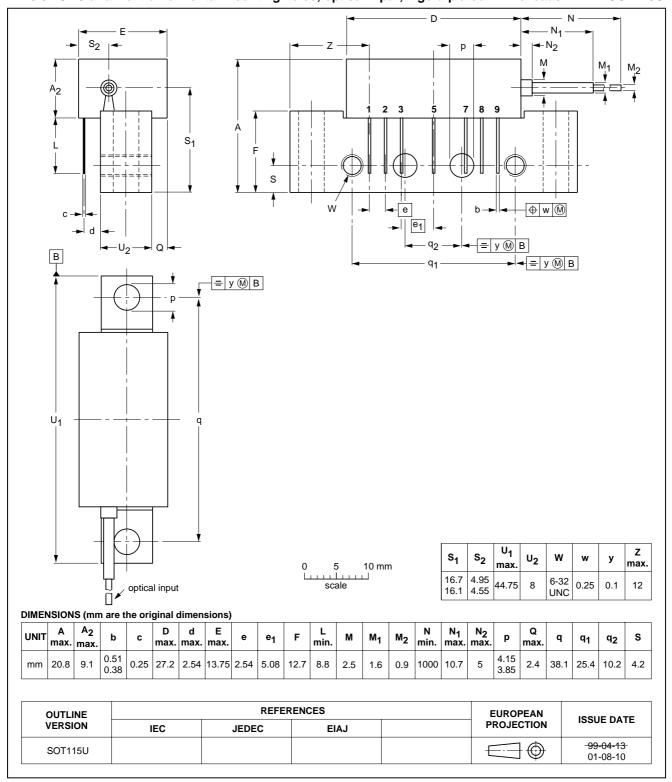
Optical receiver module

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PACKAGE OUTLINE

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; optical input; 7 gold-plated in-line leads

SOT115U



Philips Semiconductors Product specification

Optical receiver module

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DATA SHEET STATUS

DATA SHEET STATUS(1)	PRODUCT STATUS ⁽²⁾	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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CAUTION

This product is supplied in anti-static packing to prevent damage caused by electrostatic discharge during transport and handling. For further information, refer to Philips specs.: SNW-EQ-608, SNW-FQ-302A and SNW-FQ-302B.

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NOTES

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NOTES

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Contact information

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